# **Single 2-Input NAND Gate**

The NL17SZ00 is a single 2-input NAND Gate in two tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive.

# Features

- Tiny SOT-353 and SOT-553 Packages
- 2.7 ns T<sub>PD</sub> at 5 V (typ)
- Source/Sink 24 mA at 3.0 V
- Over-Voltage Tolerant Inputs
- Pin For Pin with NC7SZ00P5X, TC7SZ00FU and TC7SZ00AFE
- Chip Complexity: FETs = 20
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- These Devices are Pb-Free and are RoHS Compliant



Figure 1. Pinout (Top View)



Figure 2. Logic Symbol



# **ON Semiconductor®**

http://onsemi.com



Date Code"
– Ph\_Free Package

= Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or position may vary depending upon manufacturing location.





L1 = Specific Device Marking M = Date Code

# PIN ASSIGNMENT

| Pin | Function        |
|-----|-----------------|
| 1   | А               |
| 2   | В               |
| 3   | GND             |
| 4   | Y               |
| 5   | V <sub>CC</sub> |

# FUNCTION TABLE

| Ing | Output<br>Y = AB |   |
|-----|------------------|---|
| А   | В                | Y |
| L   | L                | Н |
| L   | Н                | Н |
| Н   | L                | Н |
| Н   | Н                | L |

# **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

# MAXIMUM RATINGS

| Symbol           | Parameter   | Value                            | Unit |
|------------------|---|----------------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage   | -0.5 to + 7.0                    | V    |
| V <sub>IN</sub>  | DC Input Voltage  | -0.5 to + 7.0                    | V    |
| V <sub>OUT</sub> | DC Output Voltage   | –0.5 to to V <sub>CC</sub> + 0.5 | V    |
| Ι <sub>ΙΚ</sub>  | DC Input Diode Current  | -50                              | mA   |
| Ι <sub>ΟΚ</sub>  | DC Output Diode Current   | -50                              | mA   |
| I <sub>OUT</sub> | DC Output Sink Current  | ±50                              | mA   |
| I <sub>CC</sub>  | DC Supply Current per Supply Pin  | ±100                             | mA   |
| T <sub>STG</sub> | Storage Temperature Range   | -65 to + 50                      | °C   |
| ΤL               | Lead Temperature, 1 mm from Case for 10 Seconds   | 260                              | °C   |
| TJ               | Junction Temperature Under Bias   | +150                             | °C   |
| $\theta_{JA}$    | Thermal Resistance SOT-353 (Note 1)<br>SOT-553  |                                  | °C/W |
| PD               | Power Dissipation in Still Air at 85°C SOT-353<br>SOT-553   |                                  | mW   |
| MSL              | Moisture Sensitivity  | Level 1                          |      |
| F <sub>R</sub>   | Flammability Rating Oxygen Index: 28 to 34  | UL 94 V-0 @ 0.125 in             |      |
| ESD              | ESD Classification Human Body Model (Note 2)<br>Machine Model (Note 3)<br>Charged Device Model (Note 4) | Class A                          |      |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.

3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

### **RECOMMENDED OPERATING CONDITIONS**

| Symbol                          | Parameter  |   | Min    | Max       | Unit |
|---------------------------------|--|---|--------|-----------|------|
| V <sub>CC</sub>                 | DC Supply Voltage  |   | 1.65   | 5.5       | V    |
| V <sub>IN</sub>                 | DC Input Voltage   | 0 | 5.5    | V         |      |
| V <sub>OUT</sub>                | DC Output Voltage  | 0 | 5.5    | V         |      |
| T <sub>A</sub>                  | Operating Temperature Range  |   | -55    | +125      | °C   |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Time $ \begin{array}{c} V_{CC} = 3.0 \ V \pm 0.3 \ V \\ V_{CC} = 5.0 \ V \pm 0.5 \ V \end{array} $ |   | 0<br>0 | 100<br>20 | ns/V |

| DC ELECTRICAL C | HARACTERISTICS |
|-----------------|----------------|
|-----------------|----------------|

|                  |   |  | V <sub>cc</sub>  | Т  | A = 25°   | С  | <b>-55°C</b> ≤ T   | A ≤ 125°C  |      |
|------------------|---|--|--|--|---|--|--|--|------|
| Symbol           | Parameter   | Condition  | (V)  | Min  | Тур   | Max  | Min  | Max  | Unit |
| V <sub>IH</sub>  | High-Level Input Voltage  |  | 1.65 to 1.95<br>2.3 to 5.5                             | 0.75 V <sub>CC</sub><br>0.7 V <sub>CC</sub>                      |   |  | 0.75 V <sub>CC</sub><br>0.7 V <sub>CC</sub>                      |  | V    |
| V <sub>IL</sub>  | Low-Level Input Voltage   |  | 1.65 to 1.95<br>2.3 to 5.5                             |  |   | 0.25 V <sub>CC</sub><br>0.3 V <sub>CC</sub>      |  | 0.25 V <sub>CC</sub><br>0.3 V <sub>CC</sub>      | V    |
| V <sub>OH</sub>  | High–Level Output Voltage<br>V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> | $\begin{split} I_{OH} &= 100 \; \mu A \\ I_{OH} &= -3 \; m A \\ I_{OH} &= -8 \; m A \\ I_{OH} &= -12 \; m A \\ I_{OH} &= -16 \; m A \\ I_{OH} &= -24 \; m A \\ I_{OH} &= -32 \; m A \end{split}$ | 1.65 to 5.5<br>1.65<br>2.3<br>2.7<br>3.0<br>3.0<br>4.5 | V <sub>CC</sub> - 0.1<br>1.29<br>1.9<br>2.2<br>2.4<br>2.3<br>3.8 | V <sub>CC</sub><br>1.4<br>2.1<br>2.4<br>2.7<br>2.5<br>4.0 |  | V <sub>CC</sub> - 0.1<br>1.29<br>1.9<br>2.2<br>2.4<br>2.3<br>3.8 |  | V    |
| V <sub>OL</sub>  | Low-Level Output Voltage<br>V <sub>IN</sub> = V <sub>IH</sub> or V <sub>OH</sub>  | $I_{OL} = 100 \ \mu A$ $I_{OL} = 3 \ m A$ $I_{OL} = 8 \ m A$ $I_{OL} = 12 \ m A$ $I_{OL} = 16 \ m A$ $I_{OL} = 24 \ m A$ $I_{OL} = 32 \ m A$   | 1.65 to 5.5<br>1.65<br>2.3<br>2.7<br>3.0<br>3.0<br>4.5 |  | 0.08<br>0.20<br>0.22<br>0.28<br>0.38<br>0.42              | 0.1<br>0.24<br>0.3<br>0.4<br>0.4<br>0.55<br>0.55 |  | 0.1<br>0.24<br>0.3<br>0.4<br>0.4<br>0.55<br>0.55 | V    |
| I <sub>IN</sub>  | Input Leakage Current   | $V_{IN} = 5.5 V \text{ or GND}$  | 0 to 5.5   |  |   | ±0.1   |  | ±1.0   | μA   |
| I <sub>OFF</sub> | Power Off Leakage<br>Current  | $V_{IN} = 5.5 V \text{ or}$<br>$V_{OUT} = 5.5 V$   | 0  |  |   | 1  |  | 10   | μΑ   |
| I <sub>CC</sub>  | Quiescent Supply Current  | $V_{IN}$ = 5.5 V or GND  | 5.5  |  |   | 1  |  | 10   | μΑ   |

### AC ELECTRICAL CHARACTERISTICS $t_R$ = $t_F$ = 3.0 ns

|                  |                   |  | V <sub>cc</sub>               | -   | T <sub>A</sub> = 25°C |      | $\text{-55°C}\leq\text{T}_{\text{A}}\leq\text{125°C}$ |      |      |
|------------------|-------------------|--|-------------------------------|-----|-----------------------|------|---|------|------|
| Symbol           | Parameter         | Condition                                | (V)                           | Min | Тур                   | Max  | Min   | Мах  | Unit |
| t <sub>PLH</sub> | Propagation Delay | $R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF     | 1.65                          | 2.0 | 5.4                   | 11.4 | 2.0   | 12   | ns   |
| t <sub>PHL</sub> | (Figure 3 and 4)  | $R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF     | 1.8                           | 2.0 | 4.5                   | 9.5  | 2.0   | 10.0 |      |
|                  |                   | $R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF     | 2.5 to 0.2                    | 0.8 | 3.0                   | 6.5  | 0.8   | 7.0  |      |
|                  |                   | $R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF     | $\textbf{3.3}\pm\textbf{0.3}$ | 0.5 | 2.4                   | 4.5  | 0.5   | 4.7  |      |
|                  |                   | $R_{L}$ = 500 $\Omega$ , $C_{L}$ = 50 pF |                               | 1.5 | 2.4                   | 5.0  | 1.5   | 5.2  |      |
|                  |                   | $R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF     | $5.0\pm0.5$                   | 0.5 | 2.0                   | 3.9  | 0.5   | 4.1  |      |
|                  |                   | $R_{L}$ = 500 $\Omega$ , $C_{L}$ = 50 pF |                               | 0.8 | 2.4                   | 4.3  | 0.8   | 4.5  |      |

### **CAPACITIVE CHARACTERISTICS**

| Symbol          | Parameter                     | Condition   | Typical | Unit |
|-----------------|-------------------------------|---|---------|------|
| C <sub>IN</sub> | Input Capacitance             | $V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$         | >4      | pF   |
| C <sub>PD</sub> | Power Dissipation Capacitance | 10 MHz, $V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$ | 25      | pF   |
|                 | (Note 5)                      | 10 MHz, $V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$ | 30      |      |

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

# NL17SZ00









# DEVICE ORDERING INFORMATION

| Device Order Number | Package Type         | SHipping <sup>†</sup> |
|---------------------|----------------------|-----------------------|
| NL17SZ00DFT2G       | SOT-353<br>(Pb-Free) | 3000 / Tape & Reel    |
| NL17SZ00XV5T2G      | SOT-553<br>(Pb-Free) | 4000 / Tape & Reel    |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NL17SZ00

# **PACKAGE DIMENSIONS**

SC-88A (SC-70-5/SOT-353) DF SUFFIX CASE 419A-02 ISSUE K







- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|     | INC                        | HES   | MILLIN   | IETERS |
|-----|----------------------------|-------|----------|--------|
| DIM | MIN                        | MAX   | MIN      | MAX    |
| Α   | 0.071                      | 0.087 | 1.80     | 2.20   |
| В   | 0.045                      | 0.053 | 1.15     | 1.35   |
| C   | 0.031 0.043<br>0.004 0.012 |       | 0.80     | 1.10   |
| D   |                            |       | 0.10     | 0.30   |
| G   | 0.026                      | BSC   | 0.65 BSC |        |
| Н   |                            | 0.004 |          | 0.10   |
| J   | 0.004                      | 0.010 | 0.10     | 0.25   |
| K   | 0.004 0.012                |       | 0.10     | 0.30   |
| Ν   | 0.008                      | REF   | 0.20     | REF    |
| S   | 0.079                      | 0.087 | 2.00     | 2.20   |

### NL17SZ00

### PACKAGE DIMENSIONS

SOT-553 **XV5 SUFFIX** CASE 463B **ISSUE B** 



 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: MULTIMETERS NOTES

CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM З.

THICKNESS OF BASE MATERIAL

|     | MILLIMETERS |      |      |       | INCHES    |       |
|-----|-------------|------|------|-------|-----------|-------|
| DIM | MIN         | NOM  | MAX  | MIN   | NOM       | MAX   |
| Α   | 0.50        | 0.55 | 0.60 | 0.020 | 0.022     | 0.024 |
| b   | 0.17        | 0.22 | 0.27 | 0.007 | 0.009     | 0.011 |
| С   | 0.08        | 0.13 | 0.18 | 0.003 | 0.005     | 0.007 |
| D   | 1.50        | 1.60 | 1.70 | 0.059 | 0.063     | 0.067 |
| Е   | 1.10        | 1.20 | 1.30 | 0.043 | 0.047     | 0.051 |
| е   | 0.50 BSC    |      |      |       | 0.020 BSC | )     |
| Г   | 0.10        | 0.20 | 0.30 | 0.004 | 0.008     | 0.012 |
| ΗE  | 1.50        | 1.60 | 1.70 | 0.059 | 0.063     | 0.067 |

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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